onsemi

1-of-8 Decoder/ Demultiplexer

High-Performance Silicon-Gate CMOS

MC74HC238A

The MC74HC238A is identical in pinout to the LS238. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

The HC238A decodes a three-bit Address to one-of-eight active-high outputs. This device features three Chip Select inputs, two active-low and one active-high to facilitate the demultiplexing, cascading, and chip-selecting functions. The demultiplexing function is accomplished by using the Address inputs to select the desired device output; one of the Chip Selects is used as a data input while the other Chip Selects are held in their active states.

Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS and TTL
- Operating Voltage Range: 2.0 V to 6.0 V
- Low Input Current: 1.0 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 100 FETs or 29 Equivalent Gates
- -Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices*

*For additional information on our Pb–Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

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A0 -

A0 C	1•	16	v _{cc}
A1 [2	15] Y0
A2 [14] Y1
CS2 [4	13] Y2
сѕз 🛛	5	12] Y3
CS1 [6	11] Y4
Y7 [7	10] Y5
GND [8	9] Y6
			•





14 Y1 ADDRESS 2 13 Y2 INPUTS A1 12 Y3 3 A2 -ACTIVE-HIGH OUTPUTS <u>11</u> Y4 10 Y5 9 Y6 7 · Y7 6 CS1 PIN 16 = V_{CC} PIN 8 = GND CHIP-4 SELECT CS2 · INPUTS 5 CS3 ·

15

• Y0

Figure 2. Logic Diagram

TRUTH TABLE

Inputs				Outputs									
CS3	CS2	CS1	A0	A1	A2	Y0	Y1	Y2	Y3	Y4	Y5	Y6	Y 7
Н	Х	х	х	х	х	L	L	L	L	L	L	L	L
Х	Н	х	Х	Х	х	L	L	L	L	L	L	L	L
Х	Х	L	х	х	х	L	L	L	L	L	L	L	L
L	L	Н	L	L	L	Н	L	L	L	L	L	L	L
L	L	Н	Н	L	L	L	Н	L	L	L	L	L	L
L	L	Н	L	н	L	L	L	Н	L	L	L	L	L
L	L	Н	Н	Н	L	L	L	L	Н	L	L	L	L
L	L	Н	L	L	Н	L	L	L	L	Н	L	L	L
L	L	Н	Н	L	Н	L	L	L	L	L	Н	L	L
L	L	Н	L	Н	Н	L	L	L	L	L	L	Н	L
L	L	Н	Н	Н	Н	L	L	L	L	L	L	L	Н

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage	–0.5 to +6.5	V	
V _{IN}	DC Input Voltage	–0.5 to V _{CC} +0.5	V	
V _{OUT}	DC Output Voltage		–0.5 to V _{CC} +0.5	V
I _{IN}	DC Input Diode Current, per Pin		±20	mA
I _{OUT}	DC Input Diode Current, Per Pin		±25	mA
I _{CC}	DC Supply Current, V _{CC} and GND Pins		±50	mA
I _{IK}	Input Clamp Current (V _{IN} < 0 or V _{IN} > V _{CC})		±20	mA
I _{OK}	Output Clamp Current (V _{OUT} < 0 or V _{OUT} > V _{CC})		±20	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 1)	SOIC-16 QFN16 TSSOP-16	126 118 159	°C/W
PD	Power Dissipation in Still Air at 25°C	SOIC-16 QFN16 TSSOP-16	995 1062 787	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V_{ESD}	ESD Withstand Voltage (Note 2)	Human Body Model Charged Device Model	2000 N/A	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

 Measured with minimum pad spacing on an FR4 board, using 76mm-by-114mm, 2-ounce copper trace no air flow per JESD51-7.
 HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage	2.0	6.0	V
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Note 3)	0	V _{CC}	V
T _A	Operating Temperature, All Package Types	-55	+125	°C
t _r , t _f	Input Rise and Fall Time $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0	1000 500 400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

3. Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS

				Guara			
Symbol Parameter		Test Conditions	v _{cc} v	–55°C to 25°C	≤ 85°C	≤ 125°C	Unit
V _{IH}	Minimum High–Level Input Voltage	$ \begin{aligned} V_{out} &= 0.1 \text{ V or } V_{CC} - 0.1 \text{ V} \\ I_{out} &\leq 20 \ \mu\text{A} \end{aligned} $	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
V _{IL}	Maximum Low-Level Input Voltage	$ \begin{array}{l} V_{out} = 0.1 \ V \ or \ V_{CC} - 0.1 \ V \\ I_{out} \ \leq \ 20 \ \mu A \end{array} $	2.0 3.0 4.5 6.0	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	0.5 0.9 1.35 1.8	V
V _{OH}	Minimum High-Level Output Voltage	$ \begin{aligned} V_{in} &= V_{IH} \text{ or } V_{IL} \\ I_{out} &\leq 20 \ \mu A \end{aligned} $	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$\label{eq:Vin} \begin{array}{ c c } V_{in} = V_{IH} \text{ or } V_{IL} & I_{out} \leq 2.4 \text{ mA} \\ & I_{out} \leq 4.0 \text{ mA} \\ & I_{out} \leq 5.2 \text{ mA} \end{array}$	3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.20 3.70 5.20	
V _{OL}	Maximum Low-Level Output Voltage	$ \begin{aligned} V_{in} &= V_{IH} \text{ or } V_{IL} \\ I_{out} &\leq 20 \ \mu A \end{aligned} $	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$\label{eq:Vin} \begin{array}{ c c } V_{in} = V_{IH} \text{ or } V_{IL} & I_{out} \leq 2.4 \text{ mA} \\ & I_{out} \leq 4.0 \text{ mA} \\ & I_{out} \leq 5.2 \text{ mA} \end{array}$	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.40 0.40 0.40	
I _{in}	Maximum Input Leakage Current	V _{in} = V _{CC} or GND	6.0	± 0.1	±1.0	± 1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0 \ \mu A$	6.0	4	40	160	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

		V _{cc}	Guara			
Symbol	Parameter	V	–55°C to 25°C	≤ 85°C	≤ 125°C	Unit
t _{PLH} , t _{PHL}	Maximum Propagation Delay, Input A to Output Y (Figures 3, 4)	2.0 3.0 4.5	135 90 27	170 125 34	205 165 41	ns
		6.0	23	29	35	
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CS1 to Output Y (Figures 3, 5)	2.0 3.0 4.5 6.0	110 85 22 19	140 100 28 24	165 125 33 28	ns
t _{PLH} , t _{PHL}	Maximum Propagation Delay, CS2 or CS3 to Output Y (Figures 3, 6)	2.0 3.0 4.5 6.0	120 90 24 20	150 120 30 26	180 150 36 31	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time, Any Output (Figures 3, 5)	2.0 3.0 4.5 6.0	75 30 15 13	95 40 19 16	110 55 22 19	ns
C _{in}	Maximum Input Capacitance	-	10	10	10	pF

		Typical @ 25°C, V_{CC} = 5.0 V		l
C _{PD}	Power Dissipation Capacitance (Per Package)*	55	pF	l

* Used to determine the no-load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.



Test	Switch Position	CL	RL
t _{PLH} / t _{PHL}	Open	50 pF	1 kΩ
t _{PLZ} / t _{PZL}	V _{CC}		
t _{PHZ} / t _{PZH}	GND		

*C_L Includes probe and jig capacitance

Figure 3. Test Circuit

SWITCHING WAVEFORMS



Figure 4.

Figure 5.



Figure 6.

PIN DESCRIPTIONS

ADDRESS INPUTS

A0, A1, A2 (Pins 1, 2, 3)

Address inputs. These inputs, when the chip is selected, determine which of the eight outputs is active-low.

CONTROL INPUTS

CS1, CS2, CS3 (Pins 6, 4, 5)

Chip select inputs. For CS1 at a high level and CS2, CS3 at a low level, the chip is selected and the outputs follow the

Address inputs. For any other combination of CS1, CS2, and CS3, the outputs are at a logic low.

OUTPUTS

Y0 - Y7 (Pins 15, 14, 13, 12, 11, 10, 9, 7)

Active-high Decoded outputs. These outputs assume a high level when addressed and the chip is selected. These outputs remain low when not addressed or the chip is not selected.



ORDERING INFORMATION Device Marking Package Shipping[†] HC238AG SOIC-16 MC74HC238ADG 48 Units / Rail MC74HC238ADR2G HC238AG SOIC-16 2500 Units / Tape & Reel MC74HC238ADR2G-Q* HC238AG SOIC-16 2500 Units / Tape & Reel MC74HC238ADTR2G HC TSSOP-16 2500 Units / Tape & Reel 238A MC74HC238ADTR2G-Q* HC TSSOP-16 2500 Units / Tape & Reel 238A

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

EXPANDED LOGIC DIAGRAM

PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER

- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSIONS & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIN	IETERS				
DIM	MIN	MAX				
Α	0.80	1.00				
A1	0.00	0.05				
A3	0.20	REF				
b	0.20	0.30				
D	2.50	BSC				
D2	0.85	1.15				
Е	3.50	BSC				
E2	1.85	2.15				
е	0.50	BSC				
K	0.20					
L	0.35	0.45				
L1		0.15				

RECOMMENDED SOLDERING FOOTPRINT*



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NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
- 3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.







DIM	MIN	NOM	MAX			
A	1.35	1.55	1.75			
A1	0.00	0.05	0.10			
A2	1.35	1.50	1.65			
b	0.35	0.42	0.49			
с	0.19	0.22	0.25			
D		9.90 BSC				
E		6.00 BSC				
E1	3.90 BSC					
е	1.27 BSC					
h	0.25	0.50				
L	0.40	0.83	1.25			
L1		1.05 REF				
Θ	0.		7'			
TOLERAN	CE OF FC	RM AND	POSITION			
aaa		0.10				
bbb		0.20				
ccc		0.10				
ddd		0.25				
eee		0.10				

MILLIMETERS



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GENERIC MARKING DIAGRAM*

16	F	A	H	A	H	A	A	A		
		XX								
		XX	XX)	XX	XX)	XX	XX	X		
	 AWLYWW 									
1	Ŧ	H	H	H	H	H	H	Ŧ	I	

XXXXX = Specific Device Code

A = Assembly Location

- WL = Wafer Lot
- Y = Year
- WW = Work Week
- G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	COLLECTOR	PIN 1.	CATHODE	PIN 1.		PIN 1.	COLLECTOR, DYE #1
2.	BASE	2.	ANODE	2.	BASE, #1	2.	
3.	EMITTER	3.	NO CONNECTION	3.	EMITTER, #1	3.	
4.	NO CONNECTION	4.	CATHODE	4.		4.	
5.	EMITTER	5.	CATHODE	5.	COLLECTOR, #2	5.	
6.	BASE	6.	NO CONNECTION	6.	BASE, #2	6.	
7.	COLLECTOR	7.	ANODE	7.	EMITTER, #2	7.	
8.	COLLECTOR	8.	CATHODE	8.	COLLECTOR, #2	8.	COLLECTOR, #4
9.	BASE	9.	CATHODE	9.	COLLECTOR, #3	9.	BASE, #4
10.	EMITTER	10.	ANODE	10.	BASE, #3	10.	EMITTER, #4
11.	NO CONNECTION	11.	NO CONNECTION	11.	EMITTER, #3	11.	BASE, #3
12.	EMITTER	12.	CATHODE	12.	COLLECTOR, #3	12.	EMITTER, #3
13.	BASE	13.	CATHODE	13.	COLLECTOR, #4	13.	BASE, #2
14.	COLLECTOR	14.	NO CONNECTION	14.	BASE, #4	14.	EMITTER, #2
15.	EMITTER	15.	ANODE	15.	EMITTER, #4	15.	BASE, #1
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1
STYLE 5:		STYLE 6:		STYLE 7:			
PIN 1.	DRAIN, DYE #1	PIN 1.	CATHODE	PIN 1.	SOURCE N-CH		
2.	DRAIN, #1	2.	CATHODE	2.	COMMON DRAIN (OUTPU	T)	
3.	DRAIN, #2	3.	CATHODE	3.	COMMON DRAIN (OUTPU	Τ)	
4.	DRAIN, #2	4.	CATHODE	4.	GATE P-CH		
5.	DRAIN, #3	5.	CATHODE	5.	COMMON DRAIN (OUTPU	Τ)	
6.	DRAIN, #3	6.	CATHODE	6.	COMMON DRAIN (OUTPU	T)	
7.	DRAIN, #4	7.	CATHODE	7.	COMMON DRAIN (OUTPU	T)	
8.	DRAIN, #4	8.	CATHODE	8.	SOURCE P-CH		
9.	GATE, #4	9.	ANODE	9.	SOURCE P-CH		
10.	SOURCE, #4	10.	ANODE	10.	COMMON DRAIN (OUTPU	Τ)	
11.	GATE, #3	11.	ANODE	11.	COMMON DRAIN (OUTPU	T)	
12.	SOURCE, #3	12.	ANODE	12.		Τ)	
13.	GATE, #2		ANODE	13.			
14.	SOURCE, #2	14.	ANODE	14.			
15.	GATE, #1	15.	ANODE	15.	COMMON DRAIN (OUTPU	T)	
16.	SOURCE, #1	16.	ANODE	16.	SOURCE N-CH		

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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